

# +5V Precision **Voltage Reference/ Temperature Transducer**

REF02

#### 1.0 **SCOPE**

This specification documents the detailed requirements for Analog Devices space qualified die including die qualification as described for Class K in MIL-PRF-38534, Appendix C, Table C-II except as modified herein.

The manufacturing flow described in the STANDARD DIE PRODUCTS PROGRAM brochure at http://www.analog.com/aerospace is to be considered a part of this specification.

This data sheet specifically details the space grade version of this product.

Part Number. The complete part number(s) of this specification follow:

**Des**cription Part Number

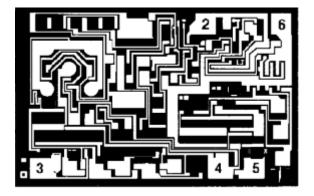
REF02-000C +5V Precision Voltage Reference / Temperature Transducer REF02R000C Radiation tested +5V Precision Voltage Reference

#### 2.0 **Die Information**

#### 2.1 **Die Dimensions**

Die Size	Die Thickness	Bond Pad Metalization			
48 mil x 74 mil	19 mil ± 2 mil	Al/Cu			

#### 3.2 **Die Picture**



- 1. NC
- $2. V_{IN}$
- 3. TEMP
- 4. GND
- 5. TRIM
- $6. V_{OUT}$ 7. NC
- 8. NC

ASD0012333

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### 3.3 <u>Absolute Maximum Ratings</u> 1/

Input Voltage (V <sub>IN</sub> )	40V dc
Output Short Circuit Duration	
Storage Temperature	65°C to +150°C
Ambient Operating Temperature Range (T <sub>A</sub> )	55°C to +125°C
Junction Temperature (T <sub>J</sub> )	150°C

Absolute Maximum Ratings Notes:

### 4.0 <u>Die Qualification</u>

In accordance with class-K version of MIL-PRF-38534, Appendix C, Table C-II, except as modified herein.

- (a) Qual Sample Size and Qual Acceptance Criteria 25/2
- (b) Qual Sample Package DIP
- (c) Pre-screen electrical test over temperature performed post-assembly prior to die qualification.

Table I - Dice Electrical Characteristics							
Parameter	Symbol	Conditions <u>1/</u>	Limit Min	Limit Max	Units		
Quiescent Supply Current	I <sub>SY</sub>	No Load		1.4	mA		
Output Adjustment Range	$\Delta V_{\text{TRIM}}$	$R_P = 10k\Omega$	±3.0		%		
Output Voltage	Vo	$I_L = 0mA$	4.985	5.015	V		
Line Regulation	LN <sub>reg</sub>	V <sub>IN</sub> = 8V to 33V		0.010	%/V		

Table I Notes:

 $1/V_{IN} = 15V$ ,  $T_A = 25^{\circ}$ C, unless otherwise specified. No external components required. Refer to section 6.0 Application Notes for more external trim details.

Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

Table II - Electrical Characteristics for Qual Samples								
Parameter	Symbol		itions I <u>/</u>	Sub- groups	Limit Min	Limit Max	Units	
		No Load		1		1.4		
Quiescent Supply Current	I <sub>SY</sub>			2, 3		2.0	mA	
			M, D, L, R <u>5</u> /	1		1.4		
Output Adjustment Range <u>6</u> /	$\Delta V_{TRIM}$	$R_P =$	$R_P = 10k\Omega$		±3.0		%	
		I <sub>L</sub> = 0mA		1	4.985	5.015	V	
Output Voltage	Vo			2, 3	4.978	5.022		
			M, D, L, R <u>5</u> /	1	4.975	5.025		
Short Circuit Current 6/	los	V <sub>O</sub> =	$V_O = 0V$		+15	+60	mA	
Sink Current <u>6</u> /	Is			1	-0.3		mA	
		I <sub>L</sub> = 0mA to 10mA		1		0.010		
Load Regulation <u>2/</u>	$LD_reg$		M, D, L, R <u>5</u> /	1		0.015	%/mA	
		$I_L = 0 m R$	A to 8mA	2, 3		0.012		
		$V_{IN} = 8V$ to 33V		1		0.010	%/V	
Line Regulation <u>2/</u>	LN <sub>reg</sub>			2, 3		0.015		
			M, D, L, R <u>5</u> /	1		0.030	1	
Load Current <u>6</u> /	IL	<u>3/</u>		1	10		mA	
Output Voltage Temperature Coefficient <u>6</u> /	TCVo	4/		8		±15	ppm/°C	

### Table II Notes:

- $V_{\text{IN}}$ = 15V, unless otherwise specified. No external components required. Line and Load Regulation specifications include effect of self heating.
- Minimum of 10mA Load Current guaranteed by Load Regulation test.
- $TCV_0 = ABS (V_{MAX} V_{MIN}) / (5V * 180^{\circ}C * 10^{-6}) \text{ where } -55^{\circ}C \le T_A \le 125^{\circ}C.$ 4/
- 5/ Radiation tested to 100Krad.
- Not tested post irradiation. Refer to section 6.0 Application Notes for more external trim details.

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Table III - Life Test Endpoint and Delta Parameter (Product is tested in accordance with Table II with the following exceptions)								
Parameter	Symbol	Sub- groups	Post Burn In Limit		Post Life Test Limit		Life Test	11
			Min	Max	Min	Max	Delta	Units
Output Voltage	Vo	1	4.979	5.021	4.973	5.027	±0.006	V
		2, 3			4.966	5.034		<b>"</b>

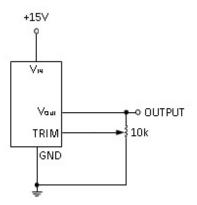
### 5.0 <u>Life Test/Burn-In Information</u>

- 5.1 HTRB is not applicable for this drawing.
- 5.2 Burn-in is per MIL-STD-883 Method 1015 test condition B.
- 5.3 Steady state life test is per MIL-STD-883 Method 1005.

#### 6.0 Application Note

- 6.1 No external components required.
- The REF02 trim terminal can be used to adjust the output voltage over a 5V ±300mV range. This feature allows the system designer to trim system errors by setting the reference to a voltage other than 5V. Of course, the output can also be set to exactly 5.000V, or to 5.12V for binary applications.

Adjustment of the output does not significantly affect the temperature performance of the device. Typically, the temperature coefficient change is 0.7ppm/°C for 100mV of output adjustment.



**Vout Trim Circuit** 

Rev	Description of Change	Date
Α	Initiate	20-DEC-01
В	Update web address. Add radiation part number and limits.	May 29, 2003
C	Update header/footer & add to 1.0 Scope description.	Feb. 26,2008
D	Add Junction Temperature150°C to 3.3 Absolute Max Ratings	March 27, 2008
E	Updated Section 4.0c note to indicated pre-screen temp testing being performed.	June 5, 2009
F	Updated fonts and sizes to ADI standard	Oct 7, 2011
G	Added application note for no external components required	Dec. 16, 2013